

L Number	Hits	Search Text	DB	Time stamp
1	258157	isolation or STI	USPAT; US-PGPUB	2004/07/14 11:48
2	16492	epitaxial with semiconductor	USPAT; US-PGPUB	2004/07/14 11:55
3	263	((dop\$3 or implant\$3) with gas with in-situ	USPAT; US-PGPUB	2004/07/14 12:04
5	0	((isolation or STI) and ((epitaxial with semiconductor) with ((dop\$3 or implant\$3) with gas with in-situ))	USPAT; US-PGPUB	2004/07/14 11:50
4	3	((epitaxial with semiconductor) with ((dop\$3 or implant\$3) with gas with in-situ))	USPAT; US-PGPUB	2004/07/14 11:53
6	5	((epitaxial with semiconductor) same ((dop\$3 or implant\$3) with gas with in-situ))	USPAT; US-PGPUB	2004/07/14 11:53
7	2	((isolation or STI) and ((epitaxial with semiconductor) same ((dop\$3 or implant\$3) with gas with in-situ))	USPAT; US-PGPUB	2004/07/14 11:53
8	24649	epitaxial with (semiconductor or polysilicn or silicon)	USPAT; US-PGPUB	2004/07/14 11:55
9	3	((epitaxial with semiconductor) with ((dop\$3 or implant\$3) with gas with in-situ))	USPAT; US-PGPUB	2004/07/14 11:55
11	16492	((epitaxial with semiconductor) with (epitaxial with (semiconductor or polysilicn or silicon)))	USPAT; US-PGPUB	2004/07/14 11:56
12	6094	((isolation or STI) and ((epitaxial with semiconductor) with (epitaxial with (semiconductor or polysilicn or silicon))))	USPAT; US-PGPUB	2004/07/14 11:56
13	357078	@ad>20020511 or @rlad>20020511	USPAT; US-PGPUB	2004/07/14 11:56
14	5290	((isolation or STI) and ((epitaxial with semiconductor) with (epitaxial with (semiconductor or polysilicn or silicon)))) not (@ad>20020511 or @rlad>20020511)	USPAT; US-PGPUB	2004/07/14 11:56
15	12	((dop\$3 or implant\$3) with gas with in-situ) with (epitaxial with (semiconductor or polysilicn or silicon))	USPAT; US-PGPUB	2004/07/14 11:56
16	11	((dop\$3 or implant\$3) with gas with in-situ) with (epitaxial with (semiconductor or polysilicn or silicon))) not (@ad>20020511 or @rlad>20020511)	USPAT; US-PGPUB	2004/07/14 11:56
17	5	((isolation or STI) and (((dop\$3 or implant\$3) with gas with in-situ) with (epitaxial with (semiconductor or polysilicn or silicon)))) not (@ad>20020511 or @rlad>20020511))	USPAT; US-PGPUB	2004/07/14 11:57
18	2859	((dop\$3 or implant\$3) with in-situ	USPAT; US-PGPUB	2004/07/14 12:04
19	111	((epitaxial with (semiconductor or polysilicn or silicon)) with ((dop\$3 or implant\$3) with in-situ))	USPAT; US-PGPUB	2004/07/14 12:04
20	58	((isolation or STI) and ((epitaxial with (semiconductor or polysilicn or silicon)) with ((dop\$3 or implant\$3) with in-situ))	USPAT; US-PGPUB	2004/07/14 12:05
21	48	((isolation or STI) and ((epitaxial with (semiconductor or polysilicn or silicon)) with ((dop\$3 or implant\$3) with in-situ))) not (@ad>20020511 or @rlad>20020511)	USPAT; US-PGPUB	2004/07/14 12:05